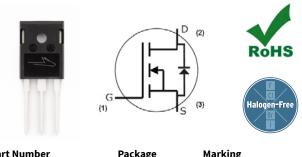


C3M0120090D

Silicon Carbide Power MOSFET C3M™ MOSFET Technology N-Channel Enhancement Mode

Features

- C3M SiC MOSFET technology
- High blocking voltage with low On-resistance
- High speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Q_{rr})
- Halogen free, RoHS compliant



Part Number	Package	Marking
C3M0120090D	TO 247-3	C3M0120090

Wolfspeed, Inc. is in the process of rebranding its products and related materials pursuant to the entity name change from Cree, Inc. to Wolfspeed, Inc. During this transition period, products received may be marked with either the Cree name and/or logo or the Wolfspeed name and/or logo.

Typical Applications

- Renewable energy
- EV battery chargers
- High voltage DC/DC converters
- Switch Mode Power Supplies
- Lighting

Benefits

- Higher system efficiency
- Reduced cooling requirements
- Increased power density
- Increased system switching frequency

Key Parameters

Parameter	Symbol	Min.	Тур.	Мах	Unit	Conditions	Note
Drain - Source Voltage	V _{DS}			900	v	T _c = 25°C	
Maximum Gate - Source Voltage	V _{GS(max)}	-8		+19		Transient	
Operational Gate-Source Voltage	V _{GS op}		-4/15			Static	Note 1
DC Continuous Drain Current	I _D			23	A	$V_{_{GS}} = 15 \text{ V}, \text{ T}_{_{C}} = 25 \text{ °C}, \text{ T}_{_{J}} \le 150 \text{ °C}$	Fig. 19 Note 2
				15		$V_{GS} = 15 \text{ V}, \text{ T}_{C} = 100 \text{ °C}, \text{ T}_{J} \le 150 \text{ °C}$	
Pulsed Drain Current	I _{DM}			50		$t_{P_{max}}$ limited by T_{jmax} $V_{GS} = 15V, T_{C} = 25 \text{ °C}$	Fig. 22
Power Dissipation	P _D			97	w	$T_{c} = 25^{\circ}C, T_{J} = 150^{\circ}C$	Fig. 20
Operating Junction and Storage Temperature	T _J , T _{stg}			-55 to +150	°C		
Solder Temperature	TL			260		According to JEDEC J-STD-020	
Mounting Torque	M _D			1 8.8	Nm Ibf-in	M3 or 6-32 screw	

Note (1): Recommended turn-on gate voltage is 15V with ±5% regulation tolerance, see Application Note PRD-04814 for additional details Note (2): Verified by design

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Electrical Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Note	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	900	-	_		$V_{GS} = 0 \text{ V}, I_{D} = 100 \mu\text{A}$		
	N N	1.8	2.1	3.5	V	$V_{DS} = V_{GS}$, $I_D = 3 \text{ mA}$	F . 11	
Gate Threshold Voltage	V _{GS(th)}	-	1.6	-		V _{DS} = V _{GS} , I _D = 3 mA, T _J = 150℃	- Fig. 11	
Zero Gate Voltage Drain Current	I _{DSS}	-	1	100	μA	$V_{DS} = 900 V, V_{GS} = 0 V$		
Gate-Source Leakage Current	I _{GSS}	-	10	250	nA	$V_{GS} = 15 V, V_{DS} = 0 V$		
Drain-Source On-State Resistance	D	_	120	155		V _{GS} = 15 V, I _D = 15 A	Fig.	
	R _{DS(on)}	-	170	-	mΩ	$V_{GS} = 15 \text{ V}, I_{D} = 15 \text{ A}, T_{J} = 150^{\circ}\text{C}$	4, 5, 6	
Transconductance			8.9		s	V _{DS} = 20 V, I _{DS} = 15 A		
Transconductance	g _{fs}	_	7.1] _	5	V _{DS} = 20 V, I _{DS} = 15 A, T _J = 150°C	- Fig. 7	
Input Capacitance	C _{iss}	-	414	-			Fig. 17, 18	
Output Capacitance	C _{oss}	-	48	-	pF	$V_{GS} = 0 V, V_{DS} = 600 V$ f = 1 Mhz		
Reverse Transfer Capacitance	C _{rss}	-	3	-		$V_{AC} = 25 \text{ mV}$		
Output Capacitance Stored Energy	E _{oss}	-	10.6	-			Fig. 16	
Turn-On Switching Energy (Body Diode FWD)	Eon	-	176	-	μJ	$V_{DS} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}, I_{D} = 15 \text{ A},$	Fig.	
Turn Off Switching Energy (Body Diode FWD)	E _{off}	-	36	-		$R_{G(ext)} = 2.5 \Omega, L = 99 \mu H, T_J = 150^{\circ}C$	26, 29	
Turn-On Delay Time	t _{d(on)}	-	6	-		$V_{DD} = 400 \text{ V}$, $V_{GS} = -4 \text{ V}/15 \text{ V}$		
Rise Time	tr	-	32	-		$I_D = 15 \text{ A}, R_{G(ext)} = 2.5 \Omega,$	Fig. 27, 29	
Turn-Off Delay Time	$t_{d(off)}$	-	14	-	ns	Timing relative to V _{DS}		
Fall Time	t _f	-	7	-		Inductive load		
Internal Gate Resistance	R _{G(int)}	_	13	_	Ω	<i>f</i> = 1 MHz, V _{AC} = 25 mV		
Gate to Source Charge	Q _{gs}	_	5	_		$V_{DS} = 400 \text{ V}, V_{GS} = -4 \text{ V}/15 \text{ V}$		
Gate to Drain Charge	Q _{gd}	_	8	_	nC	$I_{\rm D} = 15 {\rm A}$	Fig. 12	
Total Gate Charge	Qg	_	21	_		Per IEC60747-8-4 pg 21		

Reverse Diode Characteristics ($T_c = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Note	
	N	4.8	_	v	$V_{GS} = -4 V, I_{SD} = 7.5 A$	Fig.	
Diode Forward Voltage	ode Forward Voltage V _{SD} V.		$V_{GS} = -4 V, I_{SD} = 7.5 A, T_{J} = 150^{\circ}C$	8,9,10			
Continuous Diode Forward Current ¹	Is	-	15		$V_{GS} = -4 V$	Nata 1	
Diode Pulse Current ¹	I _{SM}	-	50	A	V_{GS} = -4 V, pulse width t _P limited by T _{j max}	Note 1	
Reverse Recovery Time ¹	t _{rr}	28	_	nS		Note 1	
Reverse Recovery Charge ¹	Q _{rr}	127	_	nC	$V_{GS} = -4 V, I_{SD} = 20 A, V_{R} = 400 V$ dif/dt = 600 A/µs, T ₁ = 150°C	Note 1	
Peak Reverse Recovery Current ¹	I _{rrm}	6	— A			Note 1	

Thermal Characteristics

Parameter	Symbol	Max	Unit	Note
Thermal Resistance from Junction to Case	R _{θJC}	1.3	°C/W	Fig. 21
Thermal Resistance From Junction to Ambient	R _{θJA}	40	°C/W	Fig. 21

Note:

³ Turn-off and Turn-on switching energy and timing values measured using SiC MOSFET Body Diode



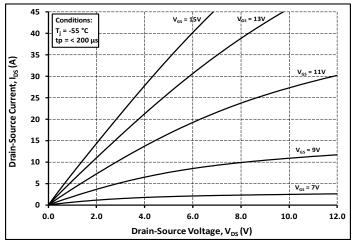
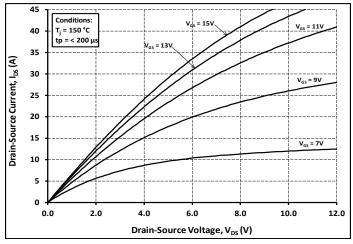
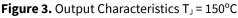
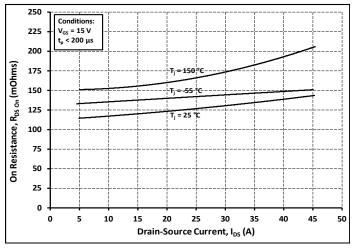
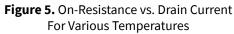


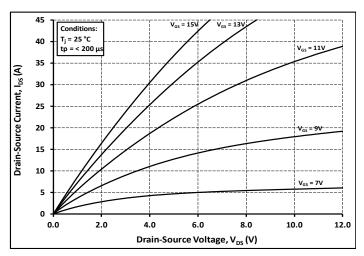
Figure 1. Output Characteristics T_J = -55°C

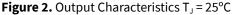












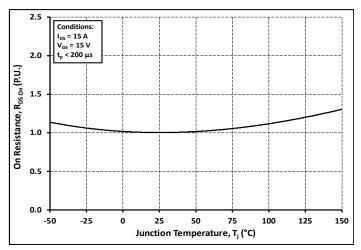
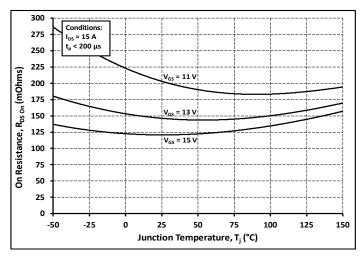
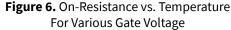


Figure 4. Normalized On-Resistance vs. Temperature

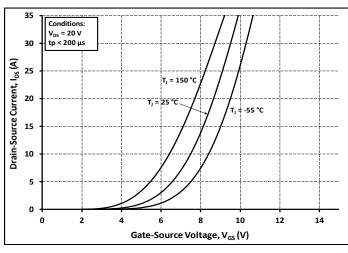


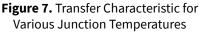


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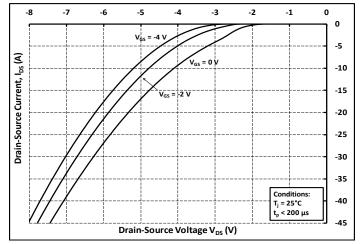
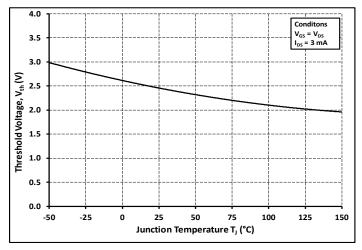
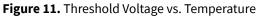


Figure 9. Body Diode Characteristic at 25°C





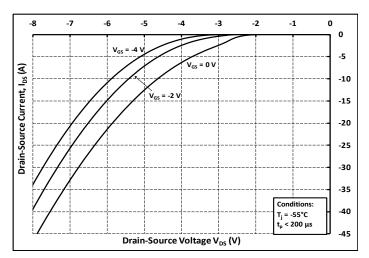


Figure 8. Body Diode Characteristic at -55°C

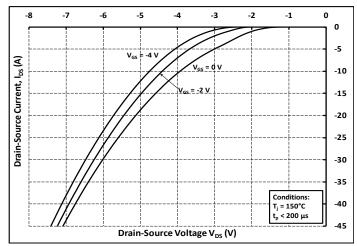


Figure 10. Body Diode Characteristic at 150°C

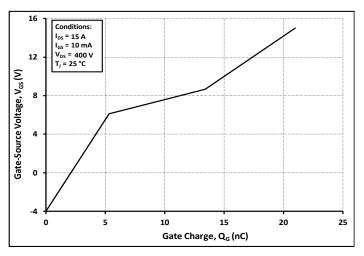


Figure 12. Gate Charge Characteristics

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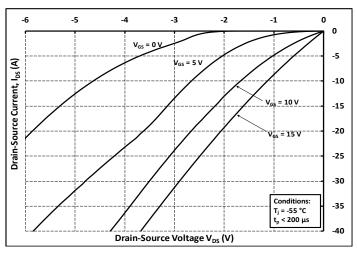


Figure 13. 3rd Quadrant Characteristic at -55°C

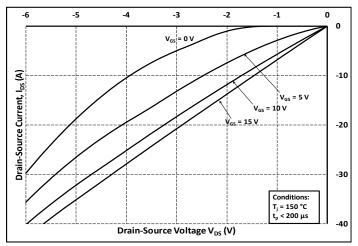


Figure 15. 3rd Quadrant Characteristic at 150°C

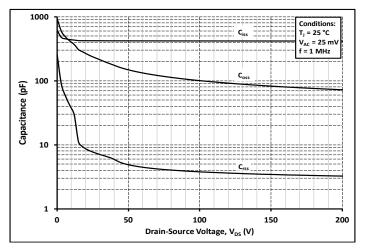


Figure 17. Capacitances vs. Drain-Source Voltage (0 - 200 V)

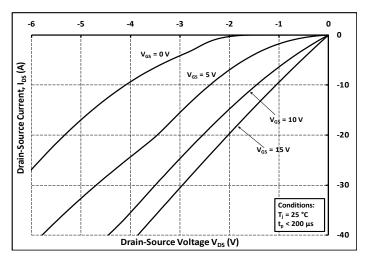


Figure 14. 3rd Quadrant Characteristic at 25°C

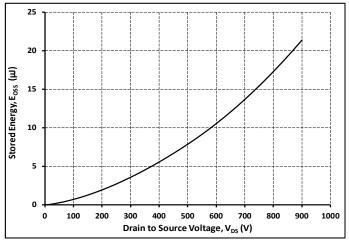


Figure 16. Output Capacitor Stored Energy

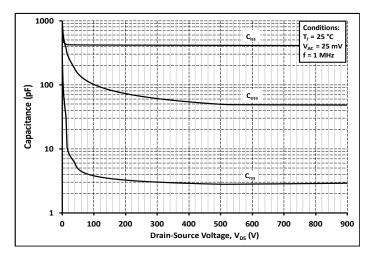
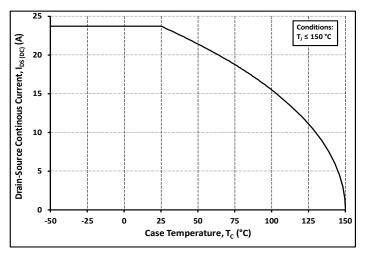


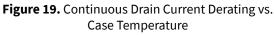
Figure 18. Capacitances vs. Drain-Source Voltage (0 - 900 V)

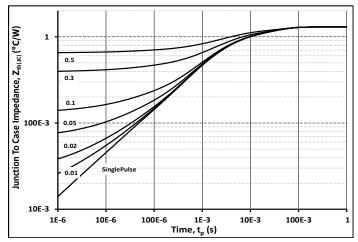
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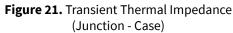
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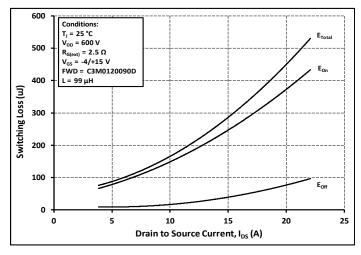


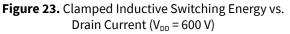












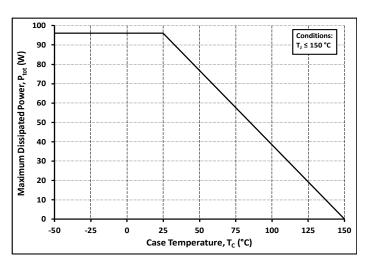


Figure 20. Maximum Power Dissipation Derating vs. Case Temperature

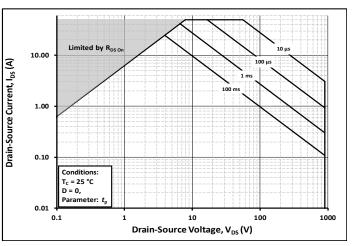


Figure 22. Safe Operating Area

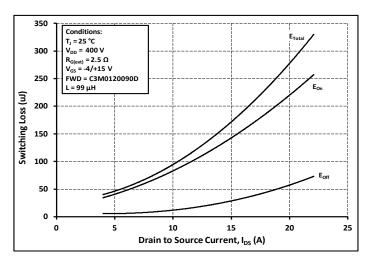


Figure 24. Clamped Inductive Switching Energy vs. Drain Current (V_{DD} = 400 V)

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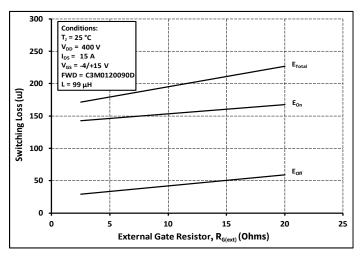


Figure 25. Clamped Inductive Switching Energy vs $R_{G(ext)}$

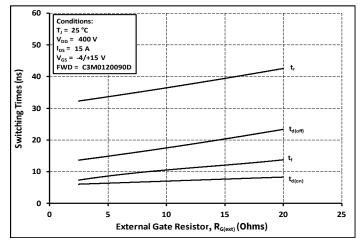


Figure 27. Switching Times vs. R_{G(ext)}

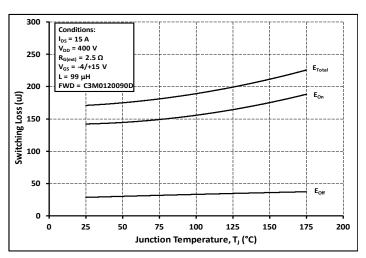


Figure 26. Clamped Inductive Switching Energy vs Temperature

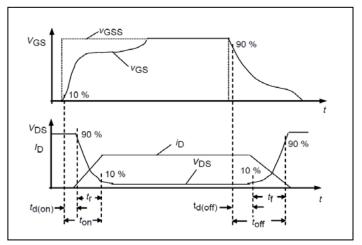


Figure 28. Switching Times Definition

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Test Circuit Schematic

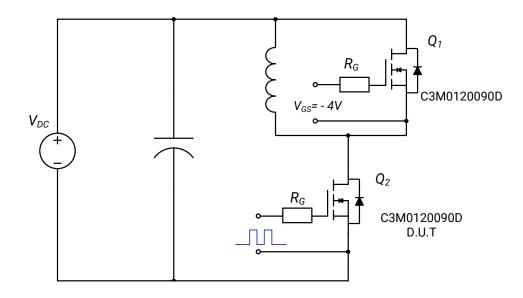


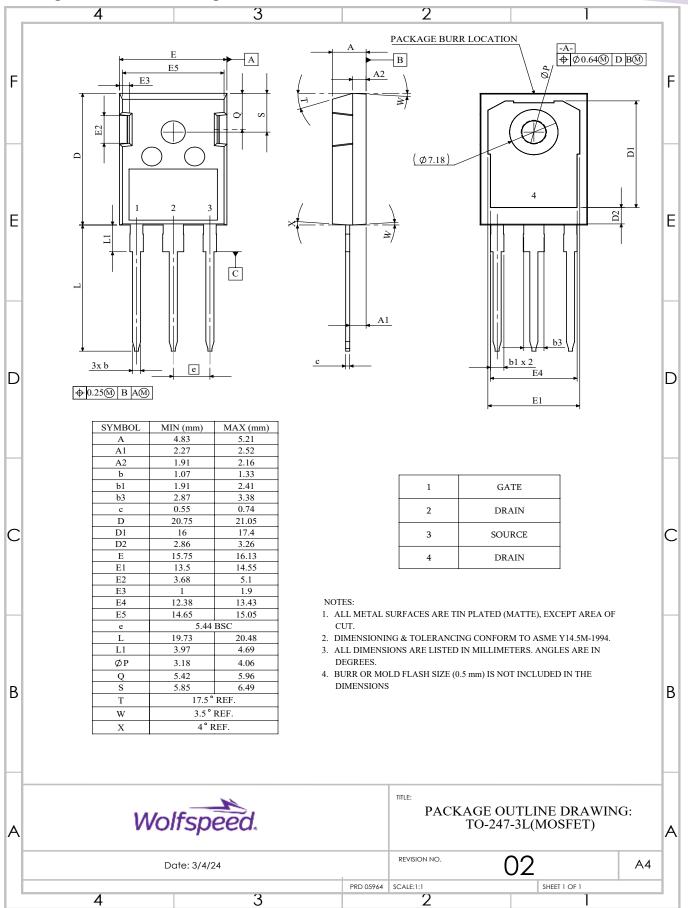
Figure 29. Clamped Inductive Switching Test Circuit

Note:

Turn-off and Turn-on switching energy and timing values measured using SiC MOSFET Body Diode as shown above.

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Package Dimensions - Package TO-247-3



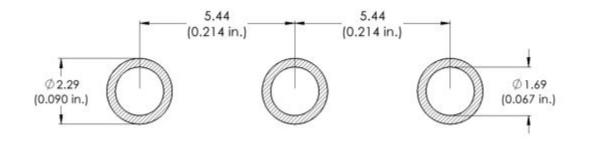
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Recommended Solder Pad Layout





Revision History

Current Revision	Date of Release	Description of Changes
2	October-2020	N/A
3	November-2023	Not Released
4	December-2023	Updated Wolfspeed branding, package drawing, package image, and solder pad layout, added Revision History Table, Table 1 layout revised
5	October - 2024	Legal Disclaimer, POD, Diode Pulse Current Symbol

Related Links

- SPICE Models
- SiC MOSFET Isolated Gate Driver reference design
- SiC MOSFET Evaluation Board

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